



DMP3010LPS

#### P-CHANNEL ENHANCEMENT MODE MOSFET POWERDI

### **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub>	I <sub>D</sub> T <sub>A</sub> = 25°C (Note 5)
-30V	$7.5 m\Omega @ V_{GS} = -10V$	-36A
	$10m\Omega @ V_{GS} = -4.5V$	-31A

#### Description

This new generation 30V P-Channel Enhancement Mode MOSFET has been designed to minimize R<sub>DS(on)</sub> and yet maintain superior switching performance. This device is ideal for use in Notebook battery power management and Loadswitch.

#### **Applications**

- Notebook Battery Power Management
- **DC-DC** Converters
- Loadswitch



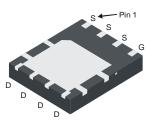
- Thermally Efficient Package-Cooler Running Applications
- High Conversion Efficiency
- Low RDS(on) Minimizes On State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications
- ESD HBM Protected up to 1kV
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### Mechanical Data

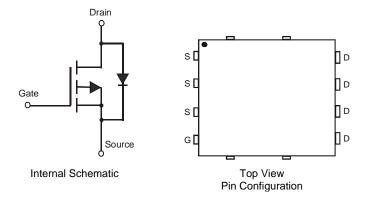
- Case: POWERDI5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Weight: 0.097 grams (approximate)



Top View



Bottom View



### Ordering Information (Note 4)

Part Number	Case	Packaging
DMP3010LPS-13	POWERDI5060-8	2500 / Tape & Reel

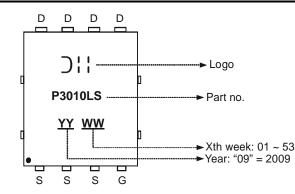
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied. Notes:

2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com.

# Marking Information





# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristi	Symbol	Value	Unit		
Drain-Source Voltage	V <sub>DSS</sub>	-30	V		
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Continuous Drain Current (Note 6) $V_{GS}$ = 10V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	-36 -29	A
Continuous Drain Current (Note 6) $V_{GS}$ = 4.5V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	I <sub>D</sub>	-31 -25	А
Continuous Drain Current (Note 5) $V_{GS}$ = 10V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	Ι <sub>D</sub>	-14.5 -11.5	A
Pulsed Drain Current (Notes 5 & 8)			I <sub>DM</sub>	-100	А
Avalanche Current (Notes 9 & 10)			I <sub>AR</sub>	-17.5	А
Repetitive Avalanche Energy (Notes 9 & 10) L = 1mH			EAR	153	mJ

### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	2.18	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 5)	R <sub>0JA</sub>	55	°C/W
Power Dissipation (Note 6)	PD	14.37	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 6)	R <sub>0JA</sub>	8.7	°C/W
Power Dissipation (Notes 6 & 7)	PD	58.7	W
Thermal Resistance, Junction to Case @T <sub>C</sub> = +25°C (Notes 6 & 7)	R <sub>θJC</sub>	2.13	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 10)			r			1	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-30	-	-	V	$V_{GS} = 0V, I_D = -250 \mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	-	-	-1.0	μA	$V_{DS} = -30V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	-	-	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 10)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	-1.1	-1.6	-2.1	V	$V_{DS} = V_{GS}$ , $I_D = -250 \mu A$	
Static Drain-Source On-Resistance	P	-	5.7	7.5	mΩ	$V_{GS} = -10V, I_D = -10A$	
	R <sub>DS (ON)</sub>	-	7.2	10	11152	$V_{GS} = -4.5V, I_D = -10A$	
Forward Transfer Admittance	Y <sub>fs</sub>	-	30	-	S	$V_{DS} = -15V, I_D = -10A$	
Diode Forward Voltage	V <sub>SD</sub>	-	-0.65	-1.0	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 11)							
Input Capacitance	Ciss	-	6234	-	pF		
Output Capacitance	Coss	-	1500	-	pF	−V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V, −f = 1.0MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	-	774	-	pF		
Gate Resistance	Rg	-	1.28	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = -10V)	Qg	-	126.2	-	nC	V <sub>DS</sub> = -15V, I <sub>D</sub> = -10A	
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg	-	59.2	-	nC	V <sub>DS</sub> = -15V, V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -10A	
Gate-Source Charge	Q <sub>gs</sub>	-	16.1	-	nC		
Gate-Drain Charge	Q <sub>gd</sub>	-	15.7	-	nC		
Turn-On Delay Time	t <sub>D(on)</sub>	-	11.4	-	ns		
Turn-On Rise Time	tr	-	9.4	-	ns	$V_{DS} = -15V, V_{GEN} = -10V,$	
Turn-Off Delay Time	t <sub>D(off)</sub>	-	260.7	-	ns	$R_G = 6\Omega, I_D = -1A$	
Turn-Off Fall Time	t <sub>f</sub>	-	99.3	-	ns	<u> </u>	

Notes: 5. Device mounted on FR-4 PCB with 1 inch square 2 oz. Copper, single sided.

5. Device mounted on FR-4 PCB with 1 into square 2 o2. Copper, single stade. 6. Device mounted on FR-4 PCB with infinite heatsink. 7. R<sub>BuC</sub> is guaranteed by design while R<sub>8CA</sub> is determined by the user's board design. 8. Repetitive rating, pulse width limited by junction temperature, 10µs pulse, duty cycle = 1%. 9. I<sub>AR</sub> and E<sub>AR</sub> rating are based on low frequency and duty cycles to keep T<sub>J</sub> = 25°C

10. Short duration pulse test used to minimize self-heating effect.

11. Guaranteed by design. Not subject to production testing.

#### DMP3010LPS

85°C = 25°C

3

-55°C

2.5

т<sub>А</sub> = 150°С

T<sub>A</sub> = 125°C

T<sub>A</sub> = -55°C

ТΔ = 25°C

20

75

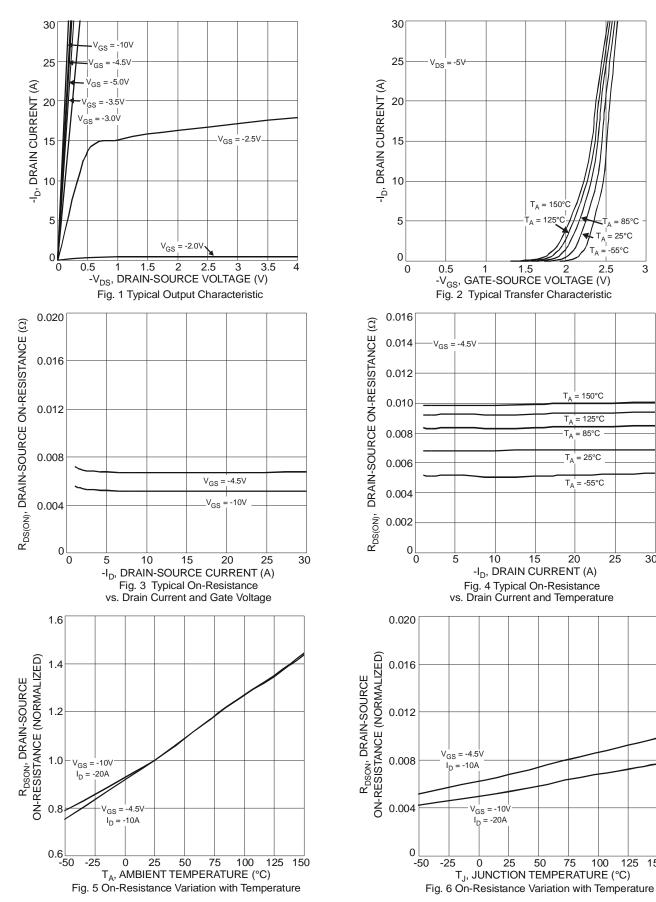
100

25

30

= 85°C TA

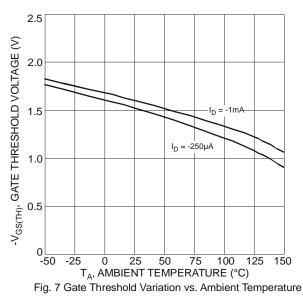


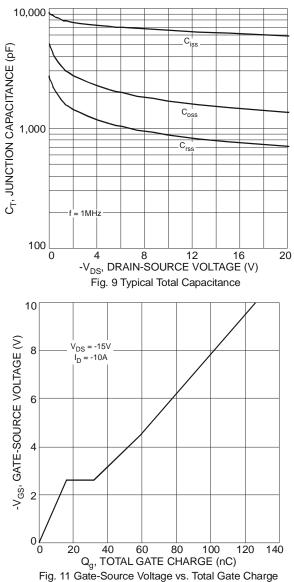


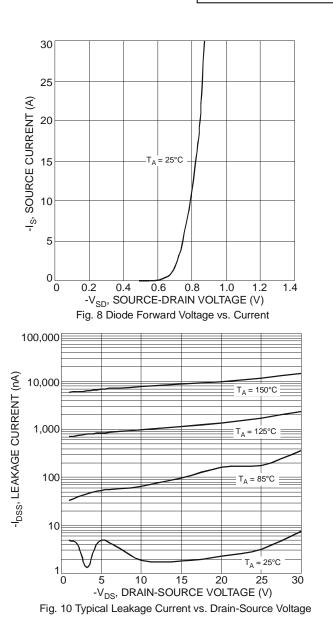
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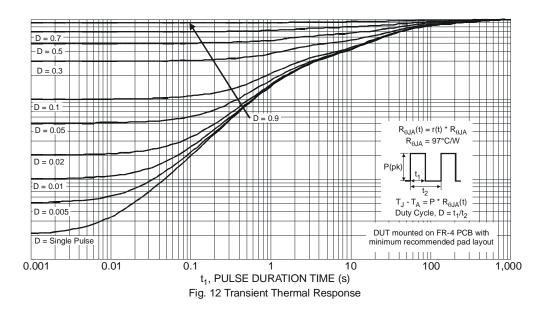






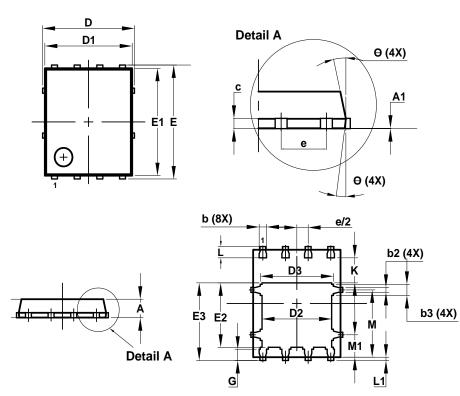






## **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

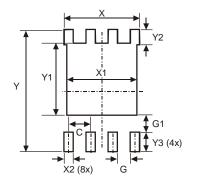


POWERDI5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
c	0.230	0.330	0.277		
D		5.15 BS(	C		
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
ш	6.15 BSC				
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
e	1.27 BSC				
G	0.51	0.71	0.61		
κ	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.050	0.20	0.175		
Μ	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10º	12º	110		
Θ1	6º	8º	7°		
All	All Dimensions in mm				



### **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	4.420
X1	4.100
X2	0.610
Y	6.610
Y1	3.810
Y2	1.020
Y3	1.270

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